



20V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 20 V Current 1A

Features

- RDS(ON), VGS@4.5V, ID@1.0A<150mΩ
- RDS(ON) , VGS@2.5V, ID@0.7A<215mΩ
- RDS(ON) , VGS@1.8V, ID@0.3A<400mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std. (Halogen Free)

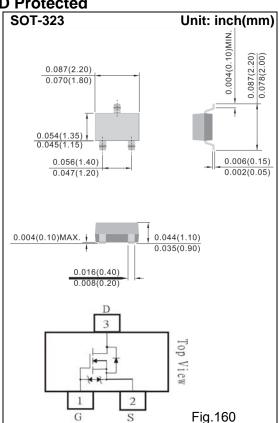
Mechanical Data

• Case: SOT-323 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0002 ounces, 0.005 grams

Marking: C04



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	1	Α
Pulsed Drain Current (Note 4)		I _{DM}	4	Α
Power Dissipation	T _a =25°C	P_{D}	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.7	0.8	1.1	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =1A	-	116	150	mΩ	
		V _{GS} =2.5V, I _D =0.7A	-	160	215		
		V _{GS} =1.8V, I _D =0.3A	-	280	400		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 2	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	Q_g	V _{DS} =10V, I _D =1A, V _{GS} =4.5V ^(Note 1,2)	_	1.6	-	nC	
Gate-Source Charge	Q_gs		_	0.31	-		
Gate-Drain Charge	Q_{gd}		-	0.41	-		
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	_	105	-	pF	
Output Capacitance	Coss		_	25	-		
Reverse Transfer Capacitance	Crss		-	15	-		
Switching							
Turn-On Delay Time	td _(on)	\/ 40\/ L 4A	-	5.8	-		
Turn-On Rise Time	tr	V_{DD} =10V, I_{D} =1A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1.2)		25.8	-	ns	
Turn-Off Delay Time	td _(off)			42	-		
Turn-Off Fall Time	tf		-	32	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					1	Α	
Diode Forward Current	I _S		-	-	ı	A	
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V		0.92	1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

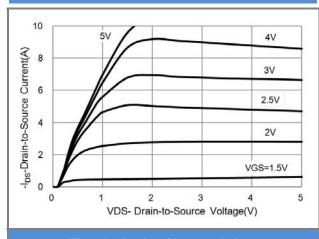


Fig.1 On-Region Characteristics

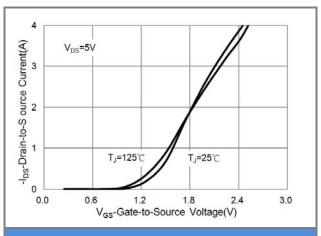


Fig.2 Transfer Characteristics

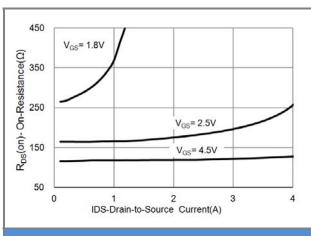


Fig.3 On-Resistance vs. Drain Current

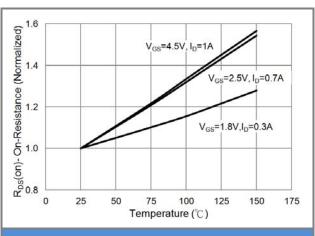


Fig.4 On-Resistance vs. Junction temperature

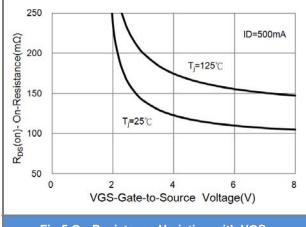
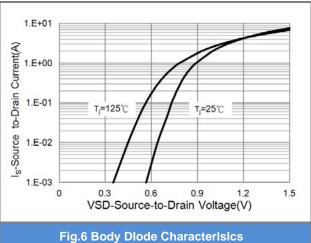


Fig.5 On-Resistance Variation with VGS.







TYPICAL CHARACTERISTIC CURVES

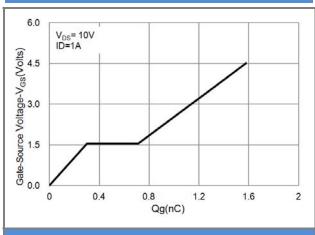


Fig.7 Gate-Charge Characteristics

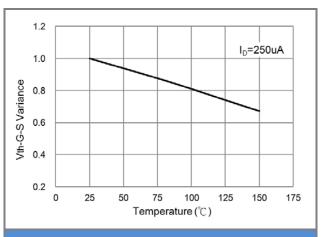


Fig.8 Threshold Voltage Variation with Temperature.

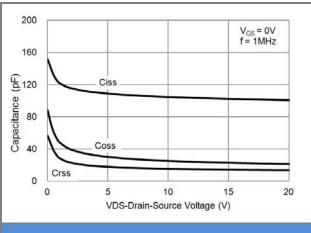


Fig.9 Capacitance vs. Drain-Source Voltage.

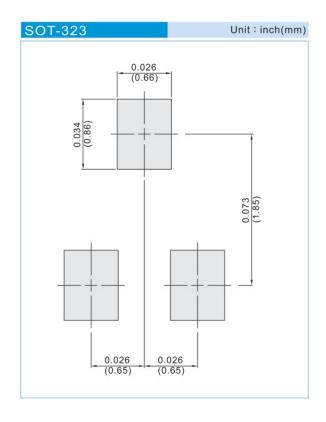




PART NO PACKING CODE VERSION

PART NO PACKING CODE VERSION	Package Type	Packing type	Marking	Version
PJC7404_R1_00001	SOT-323	3K pcs / 7" reel	C04	Halogen free
PJC7404_R2_00001	SOT-323	12K pcs / 13" reel	C04	Halogen free

MOUNTING PAD LAYOUT







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